

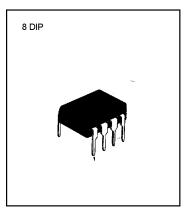
PWM CONTROLLER

The KA7552/3 are switching power control IC for wide operating frequency range. The internal circuits include pulse by pulse current limiting, protection, on/off control by external trigger, low standby current, soft start, and high current totempole output for driving a POWER MOS-FET.

Maximum duty of the KA7552 is 70% and the KA7553 is 46%. When duty is maximum, the input threshold voltage of pin2 & pin8 are not same in KA7552 and KA7553.

FEATURES

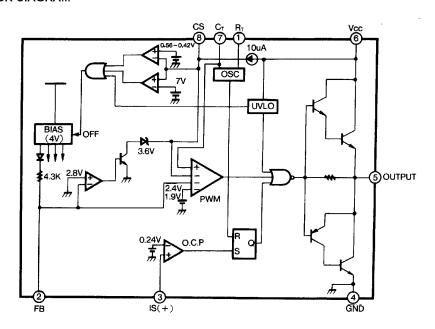
- Built-in Drive Circuits for Direct Connection POWER MOSFET (Io= \pm 1.5A)
- Wide Operating Frequency Range (5KHz ~ 600KHz)
- Pulse By Pulse Over Current Limiting
- Over Load Protection
- On/Off Control By External Trigger
- Internal UVLO
- Low Standby Current (Typ. 90uA)
- Soft Start Circuit



ORDERING IN FORMATION

Device	Package	Operating Temperature			
KA7552/3	8 DIP	-25 ~ + 85℃			

BLOCK CIAGRAM



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ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{cc}	30	V
Output Current	lo	± 1.5	А
Input Voltage at Overcurrent Detection Pin	V _{IN(IS)}	- 0.3 to 4	V
Input Voltage at FB Pin	V _{IN(FB)}	4	V
Input Current at CS Pin	I _{IN(CS)}	2	mA
Tatal Power Dissipation(Ta = 25℃)	P _D	800	mW
Operating Temperature	T _{OPR}	- 25 to 85	$^{\circ}$

ELECTRICAL CHARACTERISTICS

(V_{CC} = 18V, F_{OSC} = 135KHz, T_A = 25 $^{\circ}\mathrm{C}$, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit	
OSCILLATOR SECTION							
Initial Accuracy	Fosc	C _T = 360pF, T _J = 25°C	125	135	145	KHz	
Frequency Variation 1	$\Delta F/\Delta V$	V _{CC} = 10V to 30V	_	± 1	±3	%	
Frequency Variation 2	$\Delta F/\Delta V$	T _A = 25℃ to 85℃	_	± 1.5	_	%	
Ramp High Voltage	V _{RH}	C _T = 360pF, T _{jJ} = 25℃	2.80	3.08	3.30	V	
Ramp Low Voltage	V _{RL}	C _T = 360pF, T _J = 25°C	0.6	0.9	1.2	V	
Amplitude	Vosc	V _{PIN7} , Peak to Peak	1.80	2.18	2.50	V	
PULSE WIDTH MODULATION SECTION							
Input Threshold Voltage(Pin2)	V _{TH(FBD)}	Duty Cycle = 0%	0.6	0.75	0.95	V	
Input Threshold Voltage(Pin2)	V _{TH(FB1)} (KA7552)	Duty Cycle = Dmax 1	2.1	2.3	2.6	V	
input Threshold Voltage(Pin2)	V _{TH(FB2)} (KA7553)	Duty Cycle = Dmax 2	1.6	1.8	2.1	V	
Max. Duty Cycle	D _(Max 1) (KA7552)	-	66	70	74	%	
	D _(Max 2) (KA7553)	_	43	46	49	%	
Source Current(Pin2)	I _{SOURCE(FB)}	V _{PIN2} = 0V	- 660	- 800	- 960	uA	

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ELECTRICAL CHARACTERISTICS(Continued)

(V_{CC} = 18V, F_{OSC} = 135Khz, T_A = 25 $^{\circ}$ C, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit	
OVERCURRENT LIMIT SECTION							
Input Threshold Voltage	V _{TH(IS)}	_	0.21	0.24	0.27	٧	
Source Current(Pin3)	I _{SOURCE(IS)}	VPIN3 = 0V	-300	-200	-100	uA	
Deley Time	T _D	_	_	150	_	ns	
SOFT START SECTION	•	•	•				
Charging Current	I _{CHG}	V _{PIN8} = 0V	-15	-10	-5	uA	
Input Threshold Voltage(Pin8)	V _{TH(CSO)}	Duty Cycle = Dmax 1	0.7	0.9	1.1	٧	
Input Threshold Voltage(Pin8)	V _{TH(CS1)} (KA7552)	Duty Cycle = Dmax 2	2.2	2.4	2.6	٧	
	V _{TH(CS2)} (KA7553)		1.7	1.9	2.1	٧	
LATCH MODE SHUTDOWN CIRC	UIT SECTION						
Sink Current(Pin8)	I _{SINK(CS)}	V _{PIN8} = 6V, V _{PIN2} = 1V	25	45	65	uA	
Shutdown Threshold Voltage	V _{TH(SD,CS)}	_	6.7	7.2	7.7	٧	
OVERLOAD SHUTDOWN SECTION	N		•				
Shudown Threshold Voltage	V _{TH(SD,FB)}	_	2.6	2.8	3.1	٧	
UNDER VOLTAGE LOCKOUT SE	CTION			•			
Start-Up Threshold Voltage	V _{TH(ST)}	_	15.5	16.0	16.5	٧	
Minimum Operating Voltage	V _{OPR(Min)}	-	8.20	8.70	9.20	٧	
Hysteresis	V _{HYS}	-	6.40	7.30	8.20	٧	
ON/OFF CONTROL SECTION							
Source Current(Pin8)	I _{SOURCE(CS)}	V _{PIN8} = 0V	- 15	- 10	- 5	uA	
On Threshold Voltage	V _{TH(ON)}	V _{PIN8} : OFF->ON	0.45	0.56	0.70	٧	
Off Threshold Voltage	V _{TH(OFF)}	V _{PIN8} : ON -> OFF	0.30	0.42	0.55	٧	

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ELECTRICAL CHARACTERISTICS(Continued)

(V_{CC} = 18V, F_{OSC} = 135KHz, T_A = 25 $^{\circ}$ C, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit	
OUTPUT SECTION							
Low Output Voltage	V _{OL}	I _O = 100mA, V _{CC} = 18V	_	1.3	1.8	V	
High Output Voltage	V _{OH}	I _O = -100mA, V _{CC} = 18V	16.0	16.5	18.0	V	
Rise Time ·	T _R	NO LOAD	_	50	_	ns	
Fall Time	T _F	NO LOAD	_	50	_	ns	
OVERALL							
Stard-by Current	I _{SB}	V _{CC} = 14V	_	90	150	uA	
Operating Current	I _{CC(OPR)}	V _{PIN2} = 0V	_	9	15	mA	
Power Supply Current off	I _{CC(OFF)}	V _{PIN8} = 0V	_	1.1	1.8	mA	
Power Supply Current Shutdown	I _{CC(SD)}	V _{PIN8} = 7.6V	_	1.1	1.8	mA	

These parameters, although guaranteed, are not 100% tested in production.

NOTE: Recommend Operating Condition $R_T=3.3K\Omega\sim10K\Omega$, Oscillation Frequency = 5KHz ~600 KHz Soft Start Condensor(CS) = 0.1uF ~1 uF

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